

**LOW VOLTAGE DETECTOR WITH OUTPUT DELAY**

NO. EA-027-160309

**OUTLINE**

The RN5VD Series are CMOS-based voltage detector ICs with high detector threshold accuracy and ultra-low supply current, which can be operated at an extremely low voltage and is used for system reset as an example.

Each of these ICs consists of a voltage reference unit, a comparator, resistor net for detector threshold setting, an output driver, a hysteresis circuit, and an output delay circuit. The detector threshold is fixed with high accuracy internally and does not require any adjustment. Two output types, Nch open drain type and CMOS type are available.

Since the package for these ICs is SOT-23-5 package, high density mounting of the ICs on board is possible.

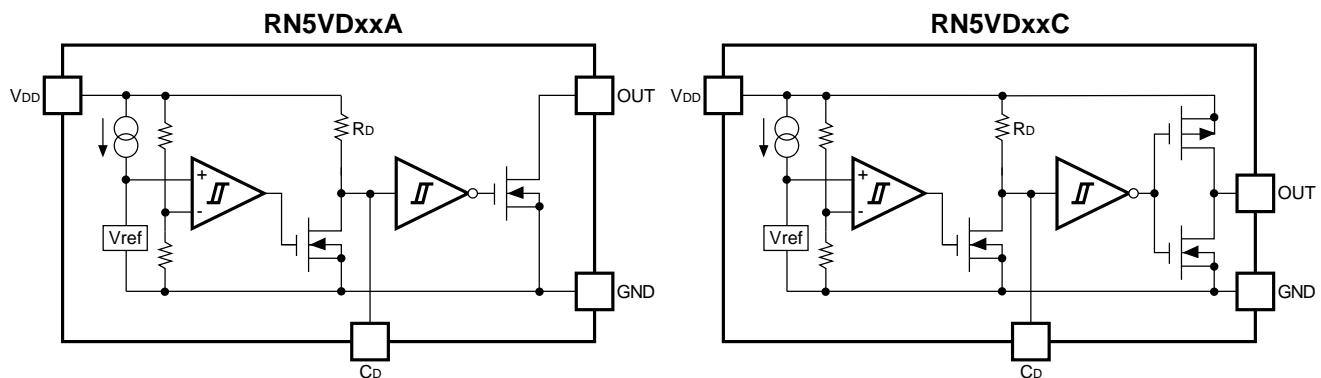
**FEATURES**

• Built-in Output Delay Circuit.....	Typ. 100ms with an external capacitor : 0.15μF
• Supply Current .....	Typ. 1.0μA (RN5VD15x, V <sub>DD</sub> =3.5V)
• Operating Voltage Range.....	0.7 to 10.0V (Topt=25°C)
• Detector Threshold Range.....	0.9V to 6.0V (0.1V steps)
• Detector Threshold Accuracy.....	±2.5%
• Temperature-Drift Coefficient of Detector Threshold .....	Typ. ±100ppm/°C
• Output Types.....	Nch Open Drain and CMOS
• Package .....	SOT-23-5

**APPLICATIONS**

- CPU and Logic Circuit Reset
- Battery Checker
- Window Comparator
- Wave Shaping Circuit
- Battery Back-up Circuit
- Power Failure Detector

## BLOCK DIAGRAMS



## SELECTION GUIDE

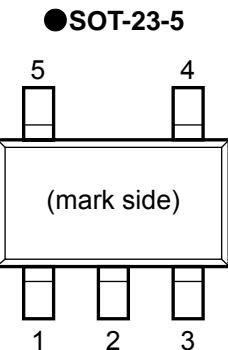
The detector threshold, and the output type for the ICs can be selected at the users' request.

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
RN5VDxx*A-TR-FE	SOT-23-5	3,000 pcs	Yes	Yes

xx: The detector threshold can be designated in the range from 0.9V(09) to 6.0V(60) in 0.1V steps.

\* : Designation of Output Type  
(A) Nch Open Drain  
(C) CMOS

## PIN CONFIGURATION



## PIN DESCRIPTION

Pin No.	Symbol	Pin Description
1	OUT	Output Pin ("L" at Detection)
2	V <sub>DD</sub>	Input Pin
3	GND	Ground Pin
4	NC	No Connection
5	C <sub>D</sub>	Pin for external capacitor (for setting output delay)

## ABSOLUTE MAXIMUM RATINGS

Symbol	Item	Ratings		Unit
V <sub>DD</sub>	Supply Voltage	12		V
V <sub>OUT</sub>	Output Voltage	CMOS	V <sub>SS</sub> -0.3 to V <sub>DD</sub> +0.3	V
		Nch	V <sub>SS</sub> -0.3~12	
I <sub>OUT</sub>	Output Current	70		mA
P <sub>D</sub>	Power Dissipation (SOT-23-5)*	420		mW
T <sub>opt</sub>	Operating Temperature Range	-40 to +85		°C
T <sub>stg</sub>	Storage Temperature Range	-55 to +125		°C
T <sub>solder</sub>	Lead Temperature (Soldering)	260°C 10s		

\* )For Power Dissipation, please refer to PACKAGE INFORMATION.

### ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the life time and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

## ELECTRICAL CHARACTERISTICS

- RN5VD09A/C

Topt=25°C

Symbol	Item	Conditions		Min.	Typ.	Max.	Unit.
-VDET	Detector Threshold			0.878	0.900	0.922	V
VHYS	Detector Threshold Hysteresis			0.027	0.045	0.063	V
Iss	Supply Current	VDD=0.8V			1.5	3.7	μA
		VDD=2.9V			0.9	2.7	
VDDH	Maximum Operating Voltage					10	V
VDDL	Minimum Operating Voltage (Note 1)	Topt=25°C			0.55	0.70	V
		-30°C≤Topt≤85°C			0.65	0.80	
IOUT	Output Current	Nch	VDS=0.05V, VDD=0.7V	0.01	0.05		mA
			VDS=0.5V, VDD=0.85V	0.05	0.50		
		Pch	VDS=-2.1V, VDD=4.5V	1.0	2.0		mA
VTCD	CD pin Threshold Voltage	VDD=0.99V		0.297	0.495	0.693	V
ICD	CD pin Sink Current	VDS=0.1V, VDD=0.7V		2.0	30		μA
		VDS=0.5V, VDD=0.85V		10.0	100.0		
RD	Delay Resistance			0.5	1.0	2.0	MΩ
$\frac{\Delta V_{DET}}{\Delta Topt}$	Detector Threshold Temperature Coefficient	-30°C≤Topt≤85°C			±100		ppm/°C

(Note 1) Minimum Operating Voltage means the value of input voltage when output voltage maintains 0.1V or less, provided that in the case of Nch Open Drain Type Products, the pull-up resistance is set at 470kΩ, and the pull-up voltage is set at 5.0V.

• RN5VD18A/C

Topt=25°C

Symbol	Item	Conditions		Min.	Typ.	Max.	Unit.
-VDET	Detector Threshold			1.755	1.800	1.845	V
VHYS	Detector Threshold Hysteresis			0.054	0.090	0.126	V
Iss	Supply Current	VDD=1.7V			2.5	5.0	μA
		VDD=3.8V			1.0	3.0	
VDDH	Maximum Operating Voltage					10	V
VDDL	Minimum Operating Voltage (Note 1)	Topt=25°C -30°C≤Topt≤85°C			0.55 0.65	0.70 0.80	V
IOUT	Output Current	Nch	VDS=0.05V, VDD=0.7V	0.01	0.05		mA
			VDS=0.5V, VDD=1.5V	1.0	2.0		
		Pch	VDS=-2.1V, VDD=4.5V	1.0	2.0		mA
VTCD	CD pin Threshold Voltage	VDD=1.98V		0.693	0.990	1.287	V
ICD	CD pin Sink Current	VDS=0.1V, VDD=0.7V		2.0	30		μA
		VDS=0.5V, VDD=1.5V		200.0	800.0		
RD	Delay Resistance			0.5	1.0	2.0	MΩ
Δ-VDET ΔTopt	Detector Threshold Temperature Coefficient	-30°C≤Topt≤85°C			±100		ppm/°C

(Note 1) Minimum Operating Voltage means the value of input voltage when output voltage maintains 0.1V or less, provided that in the case of Nch Open Drain Type Products, the pull-up resistance is set at 470kΩ, and the pull-up voltage is set at 5.0V.

## • RN5VD27A/C

Topt=25°C

Symbol	Item	Conditions		Min.	Typ.	Max.	Unit.
-VDET	Detector Threshold			2.633	2.700	2.767	V
VHYS	Detector Threshold Hysteresis			0.081	0.135	0.189	V
Iss	Supply Current	VDD=2.6V		3.5	7.0	μA	
		VDD=4.7V		1.1	3.3		
VDDH	Maximum Operating Voltage					10	V
VDDL	Minimum Operating Voltage (Note 1)	Topt=25°C -30°C≤Topt≤85°C		0.55 0.65	0.70 0.80	V	
IOUT	Output Current	Nch	VDS=0.05V, VDD=0.7V	0.01	0.05		
			VDS=0.5V, VDD=1.5V	1.0	2.0	mA	
		Pch	VDS=-2.1V, VDD=4.5V	1.0	2.0		
VTCD	CD pin Threshold Voltage	VDD=2.97V		1.188	1.485	1.782	V
ICD	CD pin Sink Current	VDS=0.1V, VDD=0.7V		2.0	30	μA	
		VDS=0.5V, VDD=1.5V		200.0	800.0		
RD	Delay Resistance			0.5	1.0	2.0	MΩ
$\frac{\Delta VDET}{\Delta Topt}$	Detector Threshold Temperature Coefficient	-30°C≤Topt≤85°C			±100		ppm/°C

( Note 1) Minimum Operating Voltage means the value of input voltage when output voltage maintains 0.1V or less, provided that in the case of Nch Open Drain Type Products, the pull-up resistance is set at 470kΩ, and the pull-up voltage is set at 5.0V.

## • RN5VD36A/C

Topt=25°C

Symbol	Item	Conditions		Min.	Typ.	Max.	Unit.
-VDET	Detector Threshold			3.510	3.600	3.690	V
VHYS	Detector Threshold Hysteresis			0.108	0.180	0.252	V
Iss	Supply Current	VDD=3.47V			4.5	9.0	μA
		VDD=5.6V			1.2	3.6	
VDDH	Maximum Operating Voltage					10	V
VDDL	Minimum Operating Voltage (Note 1)	Topt=25°C -30°C≤Topt≤85°C			0.55 0.65	0.70 0.80	V
IOUT	Output Current	Nch	VDS=0.05V, VDD=0.7V	0.01	0.05		mA
			VDS=0.5V, VDD=1.5V	1.0	2.0		
		Pch	VDS=-2.1V, VDD=4.5V	1.0	2.0		mA
VTCD	CD pin Threshold Voltage	VDD=3.96V		1.584	1.980	2.376	V
ICD	CD pin Sink Current	VDS=0.1V, VDD=0.7V		2.0	30		μA
		VDS=0.5V, VDD=1.5V		200.0	800.0		
RD	Delay Resistance			0.5	1.0	2.0	MΩ
$\frac{\Delta V_{DET}}{\Delta T_{opt}}$	Detector Threshold Temperature Coefficient	-30°C≤Topt≤85°C			±100		ppm/°C

(Note 1) Minimum Operating Voltage means the value of input voltage when output voltage maintains 0.1V or less, provided that in the case of Nch Open Drain Type Products, the pull-up resistance is set at 470kΩ, and the pull-up voltage is set at 5.0V.

## • RN5VD45A/C

Topt=25°C

Symbol	Item	Conditions		Min.	Typ.	Max.	Unit.
-VDET	Detector Threshold			4.388	4.500	4.612	V
VHYS	Detector Threshold Hysteresis			0.135	0.225	0.315	V
Iss	Supply Current	VDD=4.34V			5.5	11.0	μA
		VDD=6.5V			1.3	3.9	
VDDH	Maximum Operating Voltage					10	V
VDDL	Minimum Operating Voltage (Note 1)	Topt=25°C -30°C≤Topt≤85°C			0.55 0.65	0.70 0.80	V
IOUT	Output Current	Nch	VDS=0.05V, VDD=0.7V	0.01	0.05		mA
			VDS=0.5V, VDD=1.5V	1.0	2.0		
		Pch	VDS=-2.1V, VDD=8.0V	1.5	3.0		mA
VTCD	Cd pin Threshold Voltage	VDD=4.95V		1.980	2.475	2.970	V
ICD	Cd pin Sink Current	VDS=0.1V, VDD=0.7V		2.0	30		μA
		VDS=0.5V, VDD=1.5V		200.0	800.0		
RD	Delay Resistance			0.5	1.0	2.0	MΩ
$\frac{\Delta VDET}{\Delta Topt}$	Detector Threshold Temperature Coefficient	-30°C≤Topt≤85°C			±100		ppm/°C

(Note 1) Minimum Operating Voltage means the value of input voltage when output voltage maintains 0.1V or less, provided that in the case of Nch Open Drain Type Products, the pull-up resistance is set at 470kΩ, and the pull-up voltage is set at 5.0V.

## • RN5VD54A/C

Topt=25°C

Symbol	Item	Conditions		Min.	Typ.	Max.	Unit.
-VDET	Detector Threshold			5.265	5.400	5.535	V
VHYS	Detector Threshold Hysteresis			0.162	0.270	0.378	V
Iss	Supply Current	VDD=5.2V			6.0	12.0	μA
		VDD=7.4V			1.4	4.2	
VDDH	Maximum Operating Voltage					10	V
VDDL	Minimum Operating Voltage (Note 1)	Topt=25°C -30°C≤Topt≤85°C			0.55 0.65	0.70 0.80	V
IOUT	Output Current	Nch	VDS=0.05V, VDD=0.7V	0.01	0.05		mA
			VDS=0.5V, VDD=1.5V	1.0	2.0		
		Pch	VDS=-2.1V, VDD=8.0V	1.5	3.0		mA
VTCD	CD pin Threshold Voltage	VDD=5.94V		2.376	2.970	3.564	V
ICD	CD pin Sink Current	VDS=0.1V, VDD=0.7V		2.0	30		μA
		VDS=0.5V, VDD=1.5V		200.0	800.0		
RD	Delay Resistance			0.5	1.0	2.0	MΩ
$\frac{\Delta V_{DET}}{\Delta T_{opt}}$	Detector Threshold Temperature Coefficient	-30°C≤Topt≤85°C			±100		ppm/°C

(Note 1) Minimum Operating Voltage means the value of input voltage when output voltage maintains 0.1V or less, provided that in the case of Nch Open Drain Type Products, the pull-up resistance is set at 470kΩ, and the pull-up voltage is set at 5.0V.

## ELECTRICAL CHARACTERISTICS BY DETECTOR THRESHOLD

- RN5VD09A/C to RN5VD39A/C

Part Number.	Detector Threshold			Hysteresis			Supply Current 1			Supply Current 2			Output Current 1			Output Current 2		
	-V <sub>DET</sub> (V)			V <sub>HYS</sub> (V)			I <sub>SS1</sub> ( $\mu$ A)			I <sub>SS2</sub> ( $\mu$ A)			I <sub>OUT1</sub> (mA)			I <sub>OUT2</sub> (mA)		
	Min.	Typ.	Max.	Min.	Typ.	Max.	conditions	Typ.	Max.	conditions	Typ.	Max.	conditions	Min.	Typ.	conditions	Min.	Typ.
RN5VD09A/C	0.878	0.900	0.922	0.027	0.045	0.063		1.5	3.7		0.9	2.7				V <sub>DD</sub> = 0.85V	0.05	0.50
RN5VD10A/C	0.975	1.000	1.025	0.030	0.050	0.070		1.8	4.5							V <sub>DD</sub> = 1.0V	0.2	1.0
RN5VD11A/C	1.073	1.100	1.127	0.033	0.055	0.077		2.0	5.0									
RN5VD12A/C	1.170	1.200	1.230	0.036	0.060	0.084												
RN5VD13A/C	1.268	1.300	1.332	0.039	0.065	0.091												
RN5VD14A/C	1.365	1.400	1.435	0.042	0.070	0.098												
RN5VD15A/C	1.463	1.500	1.537	0.045	0.075	0.105												
RN5VD16A/C	1.560	1.600	1.640	0.048	0.080	0.112												
RN5VD17A/C	1.658	1.700	1.742	0.051	0.085	0.119												
RN5VD18A/C	1.755	1.800	1.845	0.054	0.090	0.126												
RN5VD19A/C	1.853	1.900	1.947	0.057	0.095	0.133												
RN5VD20A/C	1.950	2.000	2.050	0.060	0.100	0.140												
RN5VD21A/C	2.048	2.100	2.152	0.063	0.105	0.147												
RN5VD22A/C	2.145	2.200	2.255	0.066	0.110	0.154												
RN5VD23A/C	2.243	2.300	2.357	0.069	0.115	0.161												
RN5VD24A/C	2.340	2.400	2.460	0.072	0.120	0.168												
RN5VD25A/C	2.438	2.500	2.562	0.075	0.125	0.175												
RN5VD26A/C	2.535	2.600	2.665	0.078	0.130	0.182												
RN5VD27A/C	2.633	2.700	2.767	0.081	0.135	0.189												
RN5VD28A/C	2.730	2.800	2.870	0.084	0.140	0.196												
RN5VD29A/C	2.828	2.900	2.972	0.087	0.145	0.203												
RN5VD30A/C	2.925	3.000	3.075	0.090	0.150	0.210												
RN5VD31A/C	3.023	3.100	3.177	0.093	0.155	0.217												
RN5VD32A/C	3.120	3.200	3.280	0.096	0.160	0.224												
RN5VD33A/C	3.218	3.300	3.382	0.099	0.165	0.231												
RN5VD34A/C	3.315	3.400	3.485	0.102	0.170	0.238												
RN5VD35A/C	3.413	3.500	3.587	0.105	0.175	0.245												
RN5VD36A/C	3.510	3.600	3.690	0.108	0.180	0.252												
RN5VD37A/C	3.608	3.700	3.792	0.111	0.185	0.259												
RN5VD38A/C	3.705	3.800	3.895	0.114	0.190	0.266												
RN5VD39A/C	3.803	3.900	3.997	0.117	0.195	0.273												

(Note) Refer to the previously defined "Minimum Operating Voltage".

Condition 1 : T<sub>opt</sub>=25°C

Condition 2 : -30°C≤T<sub>opt</sub>≤85°C

																Topt=25°C			
Output Current 3			Minimum Operating Voltage		Cd Pin Threshold Voltage			Cd Pin Output Current 1			Cd Pin Output Current 2			Delay Resistance		Detector Threshold Tempco.			
IOUT3 (mA)			VDDL (V)		VTCD (V)			LCD1 (μA)			LCD2 (μA)			RD (MΩ)		$\frac{\Delta V_{DET}}{\Delta Topt}$ (ppm/°C)			
conditions	Min.	Typ.	Typ.	Max.	conditions	Min.	Typ.	Max.	conditions	Min.	Typ.	conditions	Min.	Typ.	Min.	Typ.	Max.	conditions	Typ.
Pch VDS=-2.1V VDD=4.5V	1.0 2.0	(Note1) Condition1 0.55 Condition2 0.65	(Note1) Condition1 0.70 Condition2 0.80	VDDX 0.3 0.35 X 1.1V	VDDX 0.5 0.5 VDDX 0.7 VDDX 0.65 VDDX 0.4 VDDX 0.5 VDDX 0.6	VDS=0.1V VDD=0.7V	2.0	30	VDS=0.5V VDD=1.5V	200	800	0.5	1.0	2.0	-30°C≤ Topt≤85°C	±100			

## RN5VD

### • RN5VD40A/C to RN5VD60A/C

Part Number.	Detector Threshold			Hysteresis			Supply Current 1			Supply Current 2			Output Current 1			Output Current 2		
	-V <sub>DET</sub> (V)			V <sub>HYS</sub> (V)			I <sub>SS1</sub> ( $\mu$ A)			I <sub>SS2</sub> ( $\mu$ A)			I <sub>OUT1</sub> (mA)			I <sub>OUT2</sub> (mA)		
	Min.	Typ.	Max.	Min.	Typ.	Max.	conditions	Typ.	Max.	conditions	Typ.	Max.	conditions	Min.	Typ.	conditions	Min.	Typ.
RN5VD40A/C	3.900	4.000	4.100	0.120	0.200	0.280												
RN5VD41A/C	3.998	4.100	4.202	0.123	0.205	0.287												
RN5VD42A/C	4.095	4.200	4.305	0.126	0.210	0.294												
RN5VD43A/C	4.193	4.300	4.407	0.129	0.215	0.301												
RN5VD44A/C	4.290	4.400	4.510	0.132	0.220	0.308	VDD= (-V <sub>DET</sub> ) -0.16V	5.0	10.0									
RN5VD45A/C	4.388	4.500	4.612	0.135	0.225	0.315												
RN5VD46A/C	4.485	4.600	4.715	0.138	0.230	0.322												
RN5VD47A/C	4.583	4.700	4.817	0.141	0.235	0.329												
RN5VD48A/C	4.680	4.800	4.920	0.144	0.240	0.336												
RN5VD49A/C	4.778	4.900	5.022	0.147	0.245	0.343												
RN5VD50A/C	4.875	5.000	5.125	0.150	0.250	0.350												
RN5VD51A/C	4.973	5.100	5.227	0.153	0.255	0.357												
RN5VD52A/C	5.070	5.200	5.330	0.156	0.260	0.364												
RN5VD53A/C	5.168	5.300	5.432	0.159	0.265	0.371												
RN5VD54A/C	5.265	5.400	5.535	0.162	0.270	0.378	VDD= (-V <sub>DET</sub> ) -0.20V	6.0	12.0									
RN5VD55A/C	5.363	5.500	5.637	0.165	0.275	0.385												
RN5VD56A/C	5.460	5.600	5.740	0.168	0.280	0.392												
RN5VD57A/C	5.558	5.700	5.842	0.171	0.285	0.399												
RN5VD58A/C	5.655	5.800	5.945	0.174	0.290	0.406												
RN5VD59A/C	5.753	5.900	6.047	0.177	0.295	0.413												
RN5VD60A/C	5.850	6.000	6.150	0.180	0.300	0.420												

(Note) Refer to the previously defined "Minimum Operating Voltage".

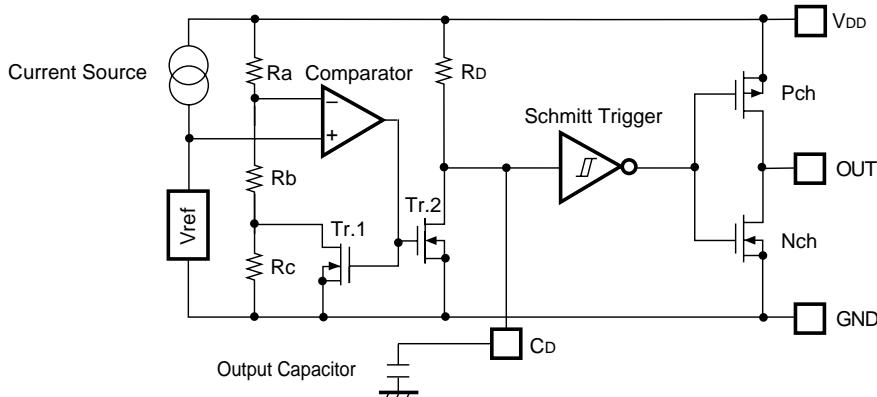
Condition 1 : T<sub>opt</sub>=25°C

Condition 2 : -30°C≤T<sub>opt</sub>≤85°C

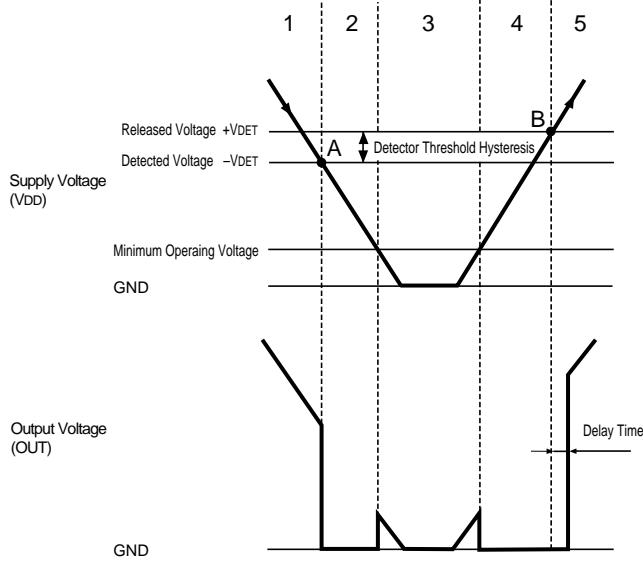
Topt=25°C

Output Current 3			Minimum Oper-ating Voltage		Cd Pin Threshold Voltage			Cd Pin Output Current 1			Cd Pin Output Current 2			Delay Resistance			Detector Threshold Tempco.		
IOUT3 (mA)			VDDL (V)		VTCD (V)			ICD1 (μA)			IOUT1 (mA)			IOUT2 (mA)			$\frac{\Delta V_{DET}}{\Delta T_{opt}}$ (ppm/°C)		
condi-tions	Min.	Typ.	Typ.	Max.	condi-tions	Min.	Typ.	Max.	condi-tions	Min.	Typ.	condi-tions	Min.	Typ.	condi-tions	Typ.	Max.	condi-tions	Typ.
Pch VDS=-2.1V VDD=8.0V	1.5	3.0	(Note1) Condition1 0.55	(Note1) Condition1 0.70	VDD= (-VDET) X1.1V	VDDX 0.4	VDDX 0.5	VDDX 0.6V	VDS= 0.1V VDD= 0.7V	2.0	30	VDS= 0.5V VDD= 1.5V	200	800	0.5	1.0	2.0	-30°C≤ Topt ≤85°C ±100	

## OPERATION



**Fig. 1 Block Diagram**



Step	Step 1	Step 2	Step 3	Step 4	Step 5
Comparator (-) Pin Input Voltage	I	II	II	II	I
Comparator Output	L	H	Indefinite	H	L
Tr. 1, 2	OFF	ON	Indefinite	ON	OFF
Output Tr.	Nch	OFF	ON	Indefinite	ON
	Pch	ON	OFF	Indefinite	OFF

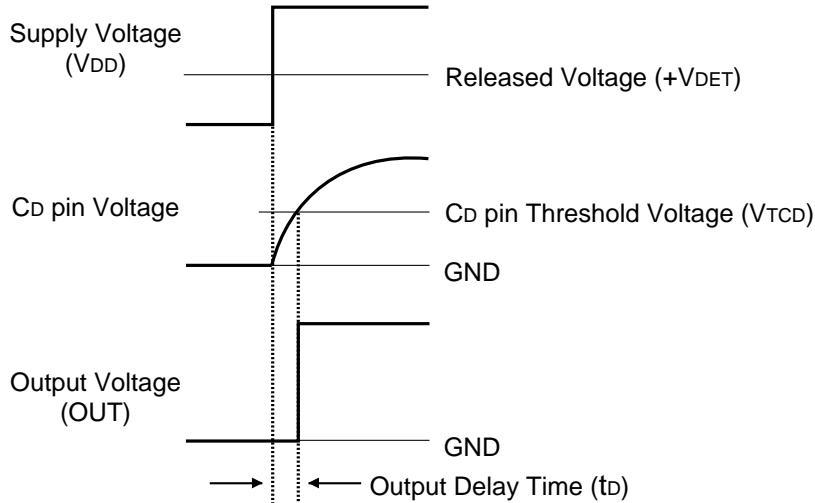
$$\text{I. } \frac{R_b + R_c}{R_a + R_b + R_c} \cdot V_{DD}$$

$$\text{II. } \frac{R_b}{R_a + R_b} \cdot V_{DD}$$

**Fig. 2 Operation Diagram**

- Step 1. Output voltage is equal to pull-up voltage.
- Step 2. When input voltage ( $V_{DD}$ ) reaches the state of  $V_{ref} \geq V_{DD} \cdot (R_b + R_c) / (R_a + R_b + R_c)$  at point A (Detected Voltage  $-V_{DET}$ ), the output of comparator is reversed, so that output voltage becomes GND. Discharging is performed from  $C_D$  pin connected to an external capacitor. No delay time is generated.
- Step 3. Output voltage becomes indefinite when power source voltage ( $V_{DD}$ ) is smaller than minimum operating voltage. When the output is pulled up,  $V_{DD}$  is output.
- Step 4. Output voltage becomes equal to GND.
- Step 5. When input voltage ( $V_{DD}$ ) reaches the state of  $V_{ref} \leq V_{DD} \cdot R_b / (R_a + R_b)$  at Point B (Released Voltage  $+V_{DET}$ ), the output of comparator is reversed, and the external capacitor is charged through  $C_D$  pin, so that output voltage becomes equal to pulled-up voltage after a delay time  $t_D (=0.69 \times 10^6 \times C_D)$ .

- Output Delay Operation



When the supply voltage crosses the released voltage ( $+V_{DET}$ ) from a low value to a value higher than the released voltage ( $+V_{DET}$ ), the Cd pin voltage starts to increase (starts to charge the external capacitor).

The output voltage is maintained at "L" level until the Cd pin voltage reaches to  $V_{TCD}$  (Cd pin threshold voltage) after that the output voltage is reversed to "H".

The time period from beginning of charging capacitor to output voltage reversing represents the output delay ( $t_D$ ).

- Output Delay Time

Delay time ( $t_D$ ) can be set accordance with the capacitance  $C_D$  of external capacitor as below

$$t_D = 0.69 \times 10^6 \times C_D \text{ (s)}$$

## TEST CIRCUITS

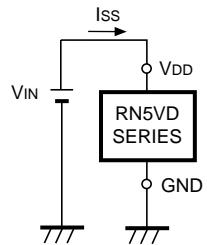


Fig. 3 Supply Current test Circuit

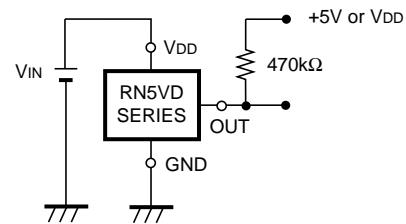


Fig. 4 Detector Threshold Test Circuit

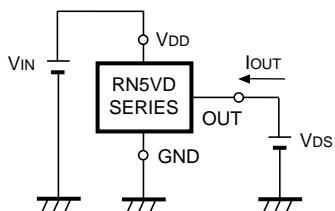


Fig. 5 Nch Driver Output Current Test Circuit

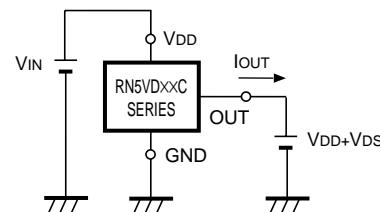


Fig. 6 Pch Driver Output Current Test Circuit

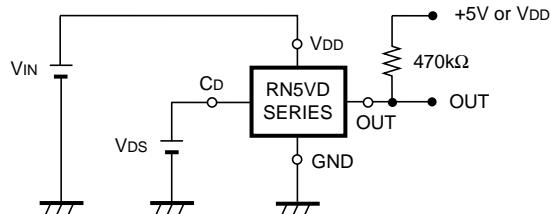


Fig. 7 Cd pin Threshold Voltage Test Circuit

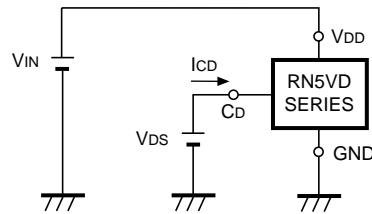


Fig. 8 Cd pin Sink Current Test Circuit

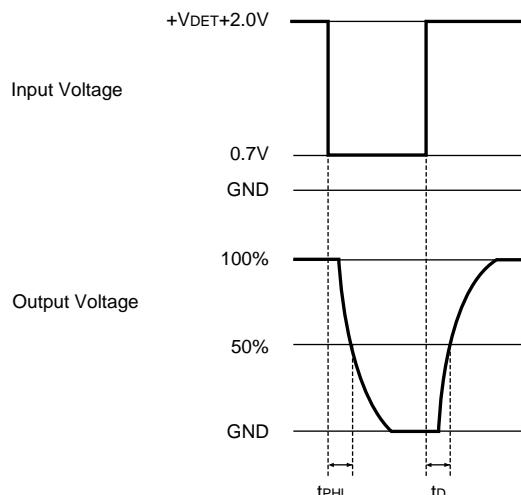
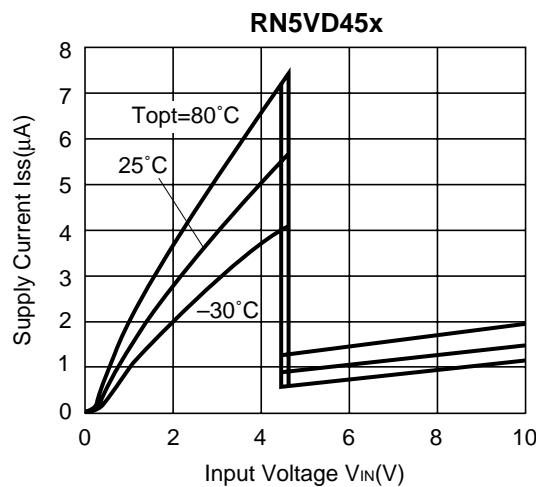
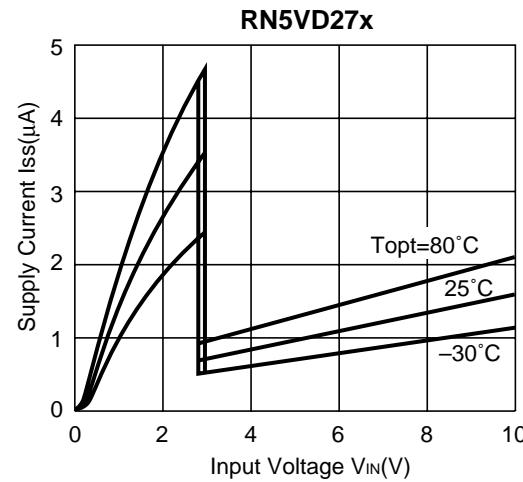
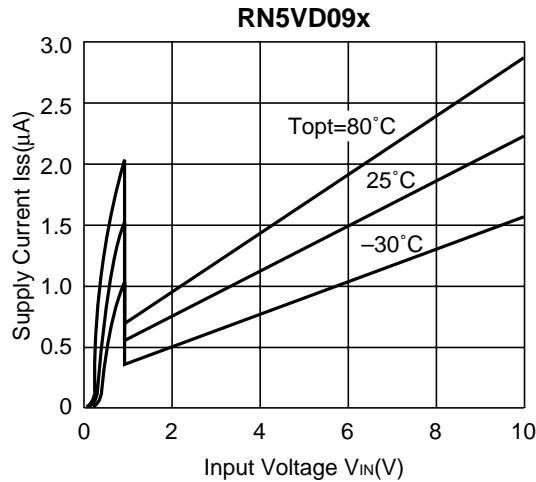


Fig. 9 Output Delay Time Test Circuit

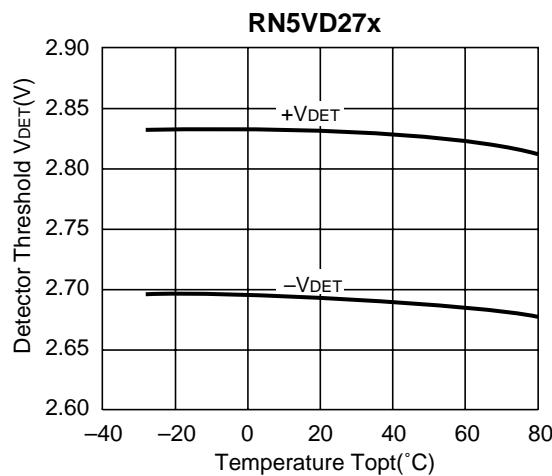
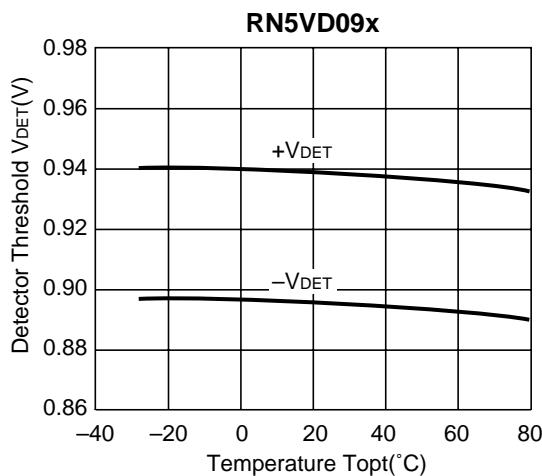
\*) at Fig.4,7,9. CMOS Output Type does not need a pull-up resistor.

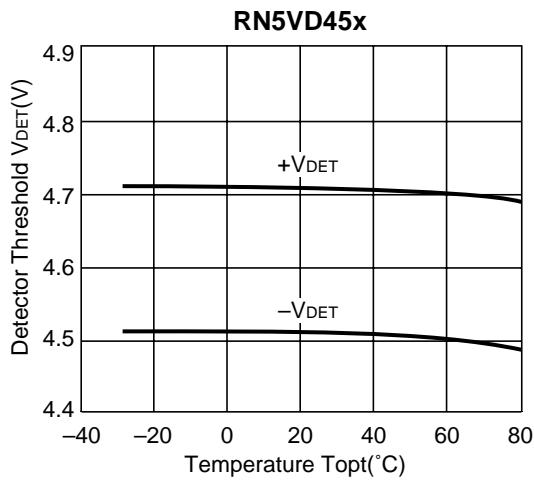
## TYPICAL CHARACTERISTICS

### 1) Supply Current vs. Input Voltage

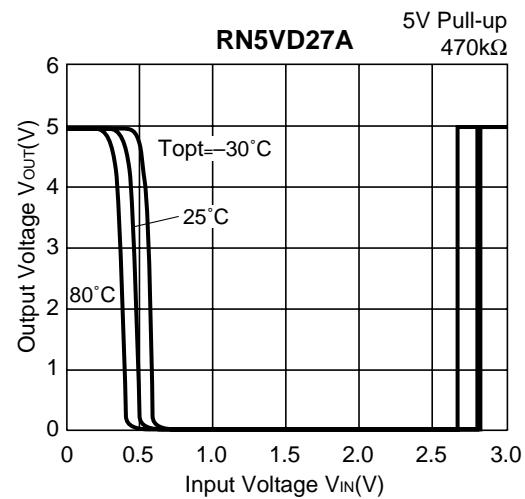
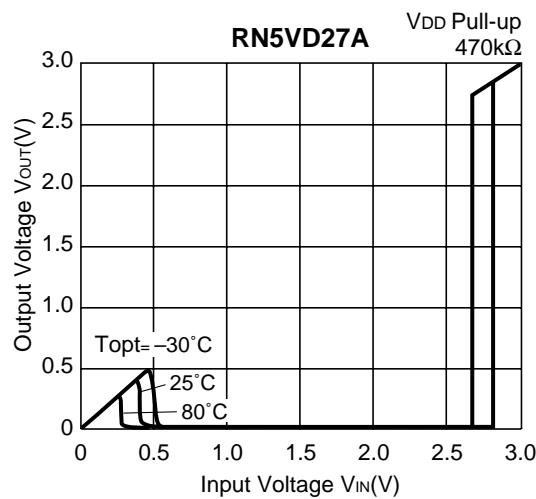
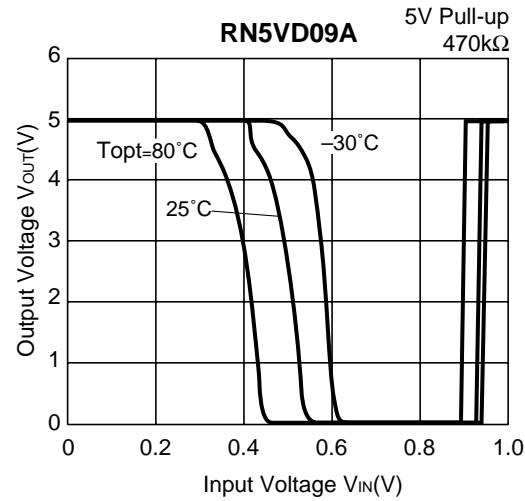
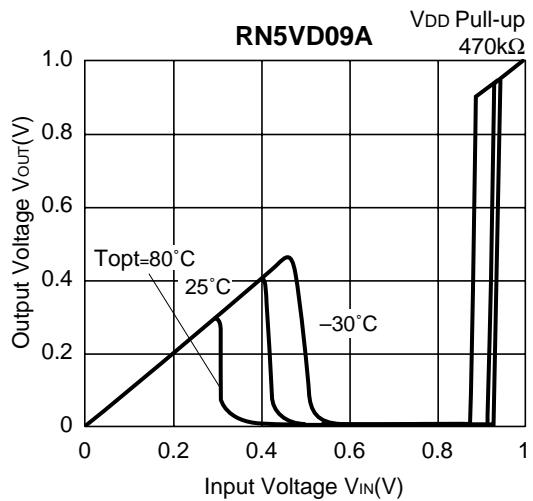


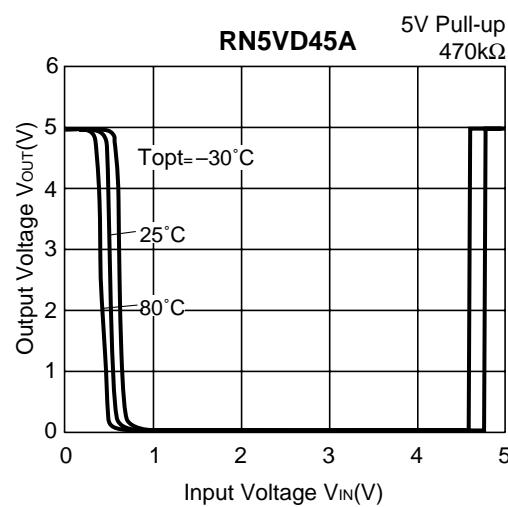
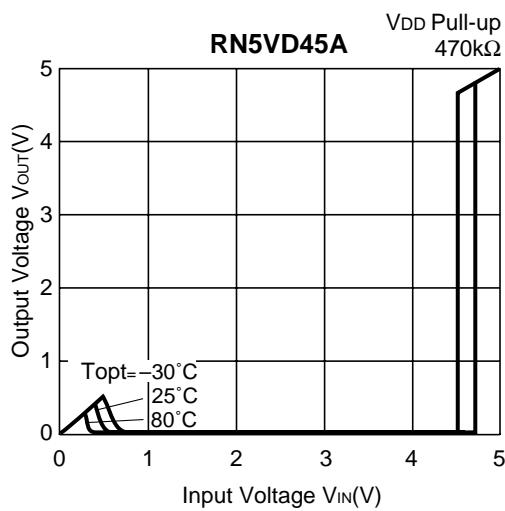
### 2) Detector Threshold vs. Temperature



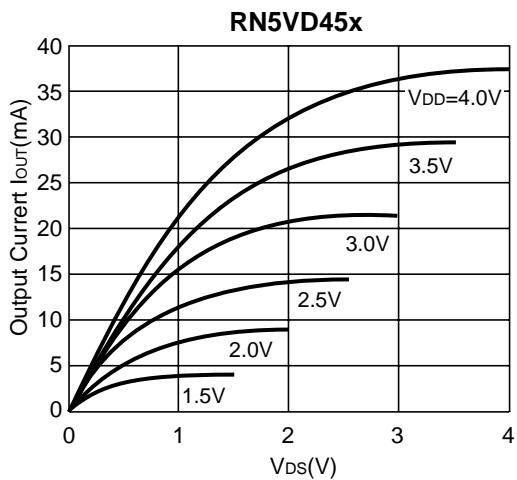
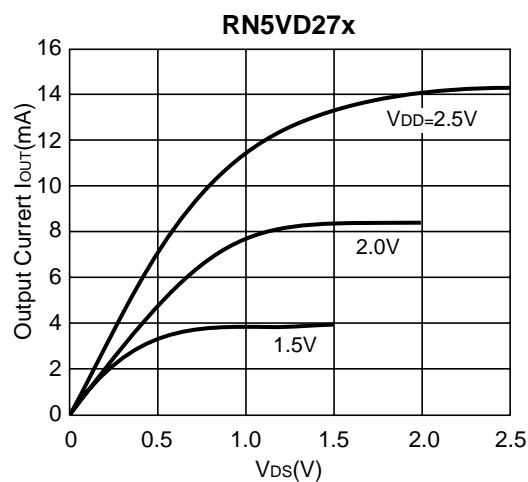
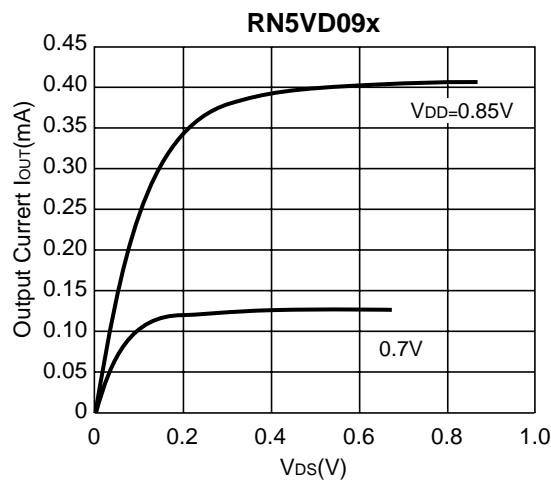


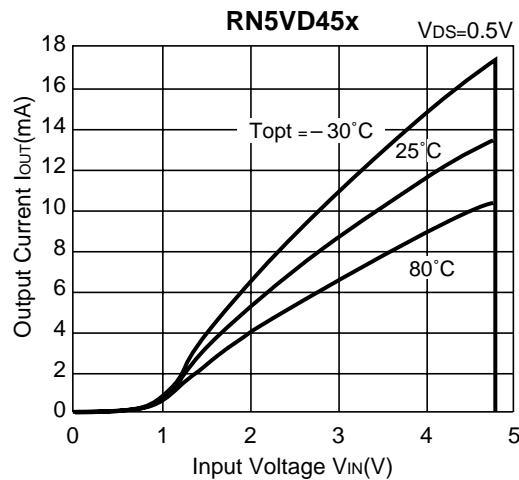
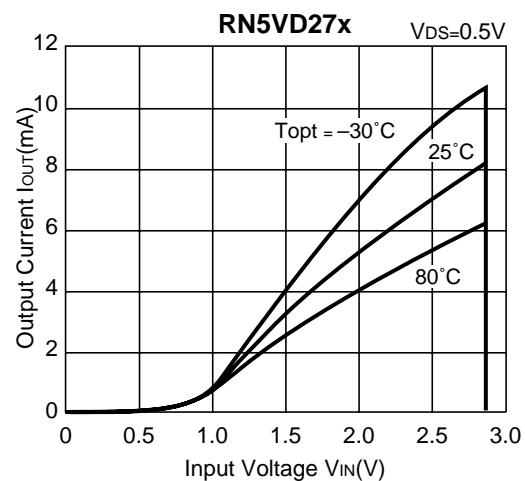
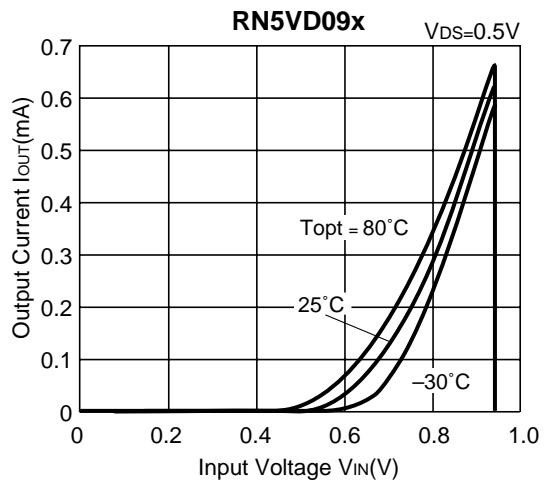
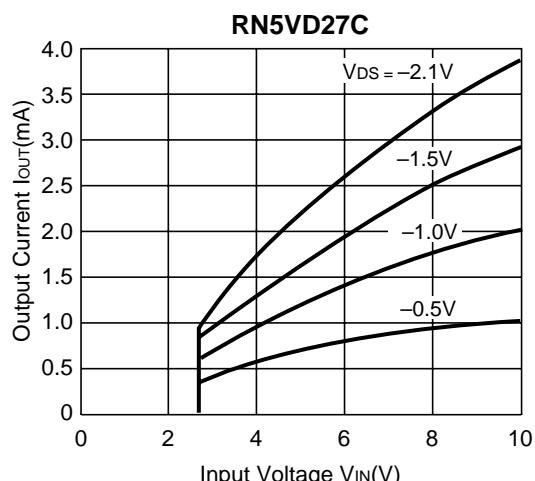
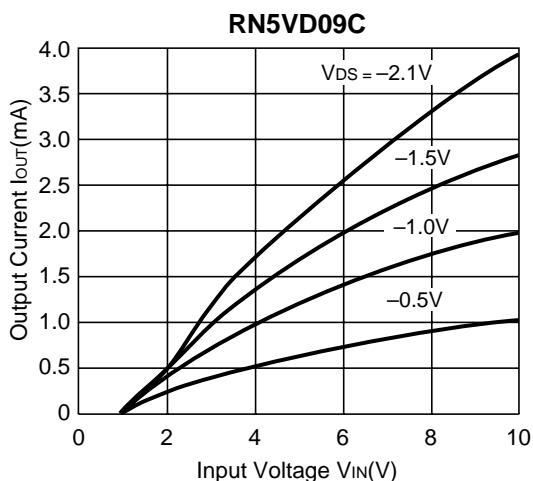
### 3) Output Voltage vs. Input Voltage

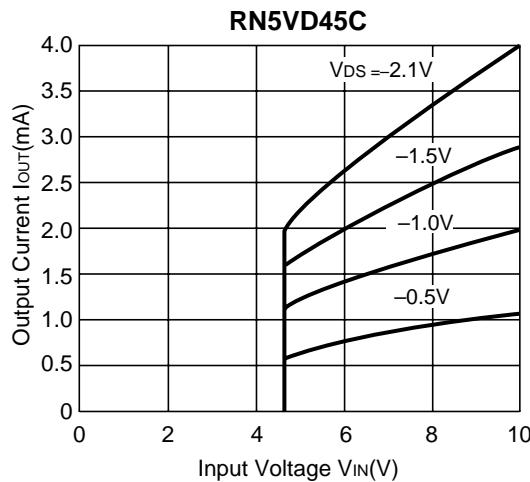




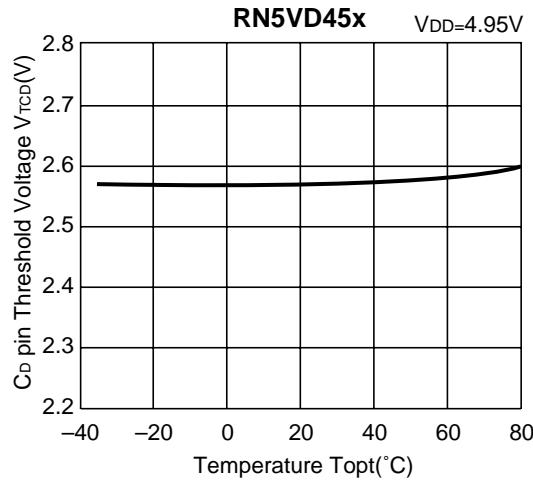
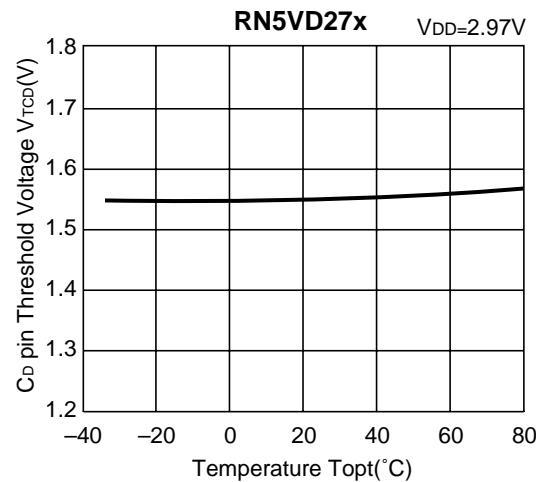
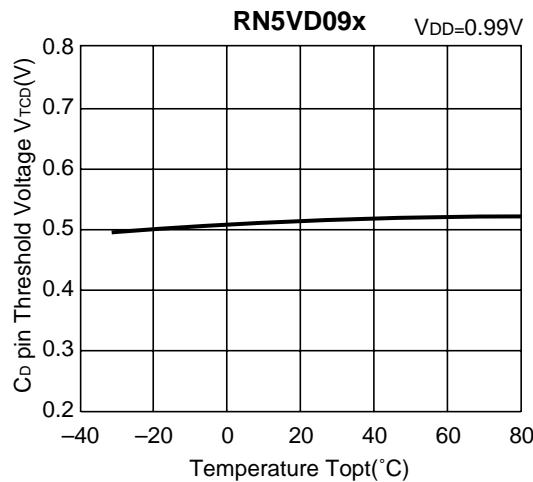
#### 4) Nch Driver Output Current vs. $V_{DS}$

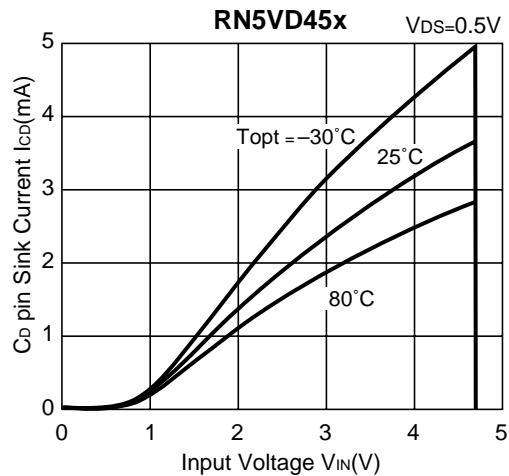
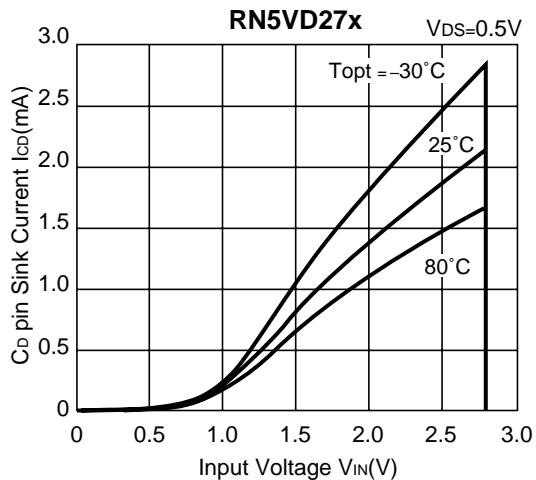
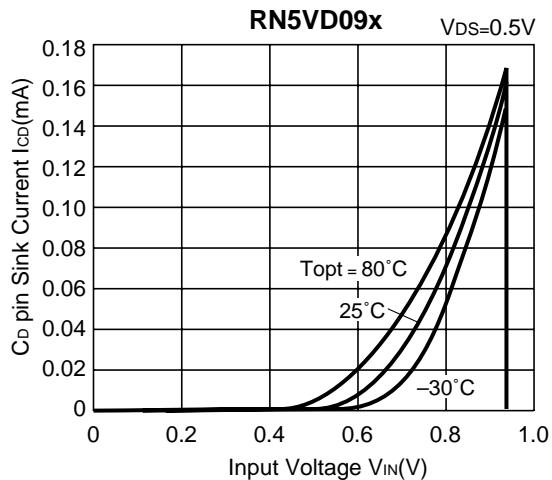
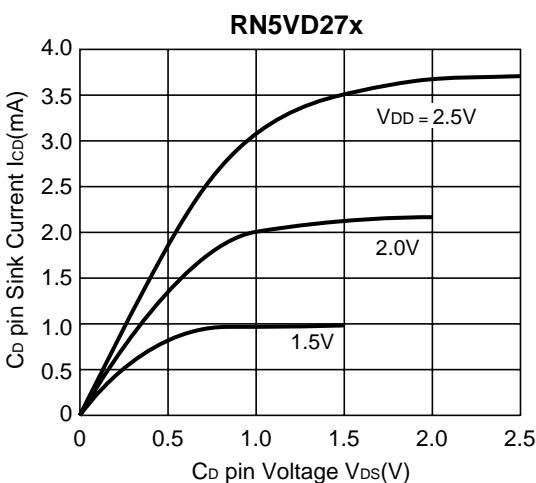
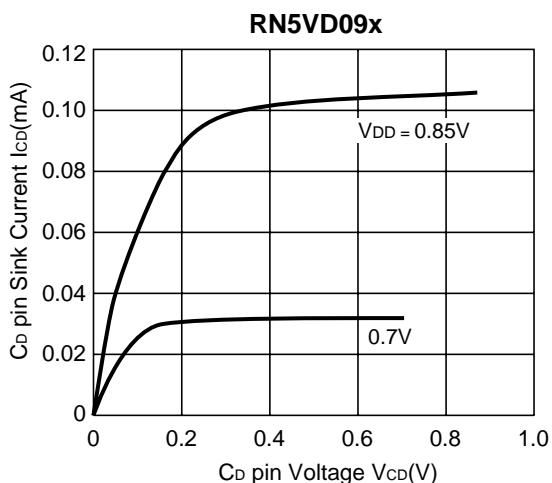


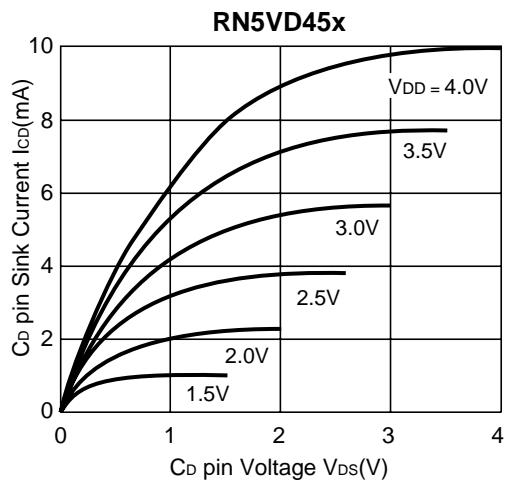
**5) Nch Driver Output Current vs. Input Voltage****6) Pch Driver Output Current vs. Input Voltage**



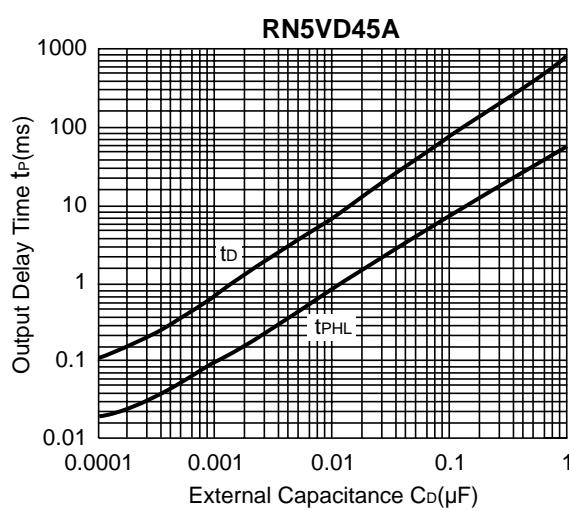
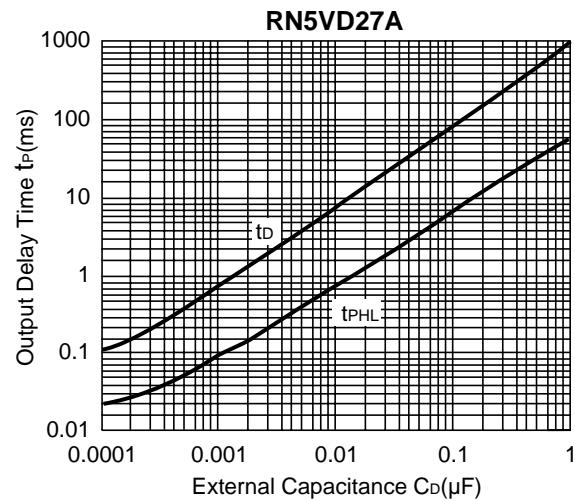
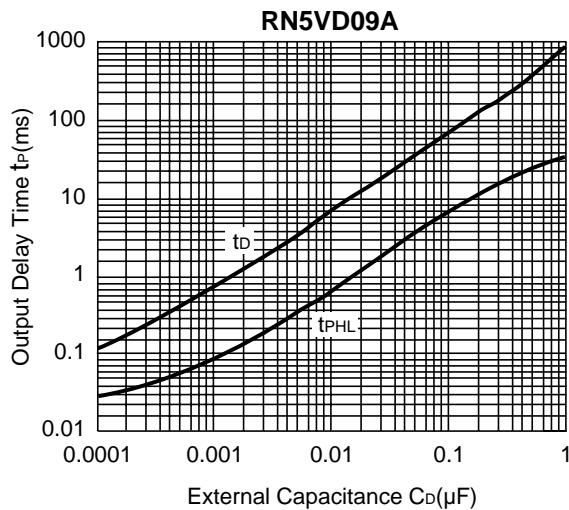
#### 7) $C_D$ pin Threshold Voltage vs. Temperature



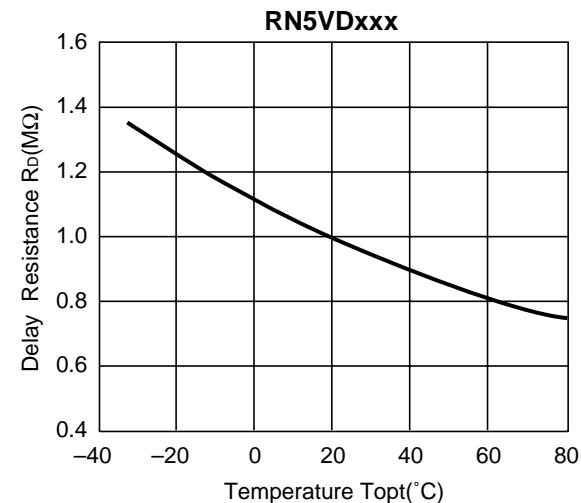
**8) CD pin Sink Current vs. Input Voltage****9) CD pin Sink Current vs. CD pin Voltage**



#### 10) Output delay Time vs. External Capacitance



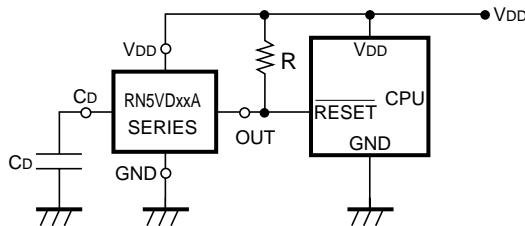
#### 11) Delay Resistance vs. Temperature



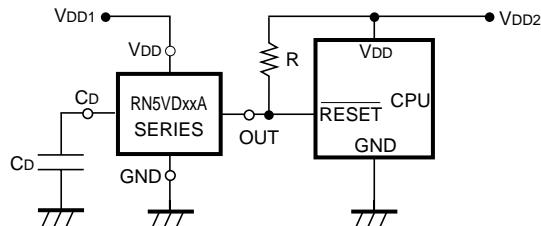
## TYPICAL APPLICATIONS

- RN5VDxxA CPU Reset Circuit (Nch Open Drain Output)

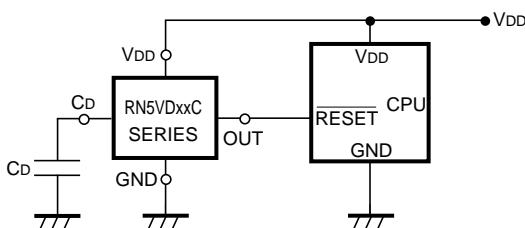
(1) Input Voltage to RN5VDxxA is the same as the input voltage to CPU.



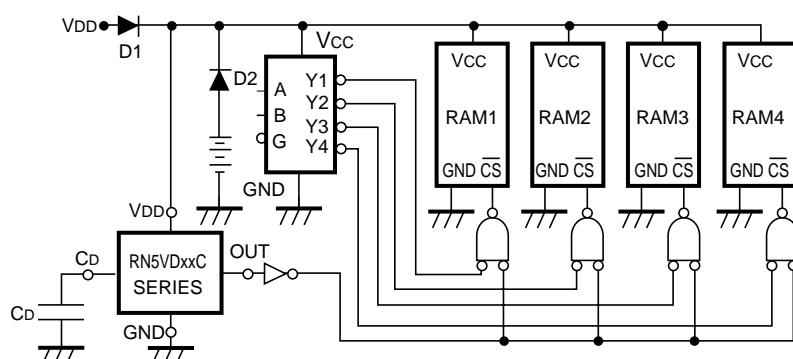
(2) Input Voltage to RN5VDxxA is different from the input voltage to CPU.



- RN5VDxxC CPU Reset Circuit (CMOS Output)



- Memory Back-up Circuit



• Manual Reset Circuit



## TECHNICAL NOTES

### When connecting resistors to the device's input pin

When connecting a resistor (R1) to an input of this device, the input voltage decreases by [Device's Consumption Current] x [Resistance Value] only. And, the cross conduction current<sup>\*1</sup>, which occurs when changing from the detecting state to the release state, is decreased the input voltage by [Cross Conduction Current] x [Resistance Value] only. And then, this device will enter the re-detecting state if the input voltage reduction is larger than the difference between the detector voltage and the released voltage.

When the input resistance value is large and the VDD is gone up at mildly in the vicinity of the released voltage, repeating the above operation may result in the occurrence of output.

As shown in Figure A/B, set R1 to become 100 kΩ or less as a guide, and connect  $C_{IN}$  of 0.1 μF and more to between the input pin and GND. Besides, make evaluations including temperature properties under the actual usage condition, with using the evaluation board like this way. As a result, make sure that the cross conduction current has no problem.

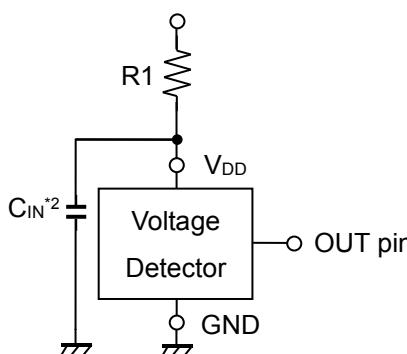


Figure A

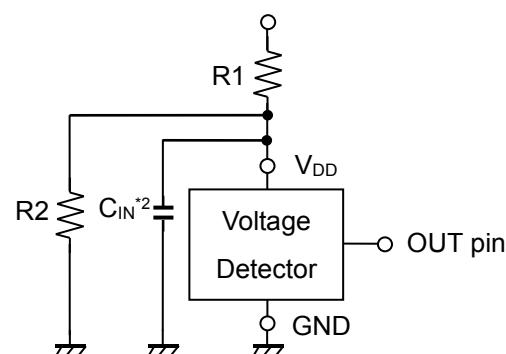


Figure B

<sup>\*1</sup> In the CMOS output type, a charging current for OUT pin is included.

<sup>\*2</sup> Note the bias dependence of capacitors.



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